N-Channel 70-V (D-S) MOSFET

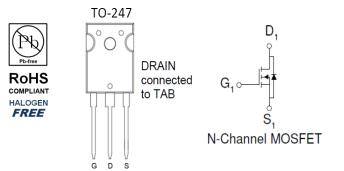
Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- Automotive Systems
- DC/DC Conversion Circuits
- Battery Powered Power Tools

PRODUCT SUMMARY			
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
70	3.5 @ V _{GS} = 10V	210 ^a	
70	4.5 @ V _{GS} = 7V	210	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			70	V	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current ^a	T _C =25°C	I _D	210	А	
Pulsed Drain Current ^b		I _{DM}	840	A	
Continuous Source Current (Diode Conduction) ^a	T _C =25°C	ا _s	210	А	
Power Dissipation ^a	T _C =25°C	PD	500	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient °	$R_{ extsf{ heta}JA}$	40	°C/W		
Maximum Junction-to-Case	$R_{ extsf{ heta}JC}$	0.29	0/10		

Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature
- c. Surface Mounted on 1" x 1" FR4 Board.

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit	
Static							
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$			±100	nA	
Zoro Coto Voltogo Droin Current		$V_{DS} = 56 \text{ V}, V_{GS} = 0 \text{ V}$			1	uА	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 56 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uЛ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	250			Α	
Drain Course On Desistance a	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 50 \text{ A}$			3.5	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 7 \text{ V}, \text{ I}_{D} = 40 \text{ A}$			4.5		
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		81		S	
Diode Forward Voltage ^a	V_{SD}	$I_{S} = 105 \text{ A}, V_{GS} = 0 \text{ V}$		1.1		V	
		Dynamic ^b					
Total Gate Charge	Qg	$V_{DS} = 35 V, V_{GS} = 7 V,$		112		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = 33 V, V_{GS} = 7 V,$ $I_{D} = 20 A$		50			
Gate-Drain Charge	Q_gd	1 <u>0</u> – 20 A		32		1	
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 35 \text{ V}, \text{ R}_{1} = 1.8 \Omega,$		91			
Rise Time	t _r	$V_{DS} = 35 V, R_L - 1.0 \Omega,$ $I_D = 20 A,$		69		20	
Turn-Off Delay Time	t _{d(off)}	$V_{\text{GEN}} = 20 \text{ A},$ $V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$		132		ns	
Fall Time	t _f			53			
Input Capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 Mhz		9136			
Output Capacitance	C _{oss}			944		рF	
Reverse Transfer Capacitance	C _{rss}			815			

Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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8

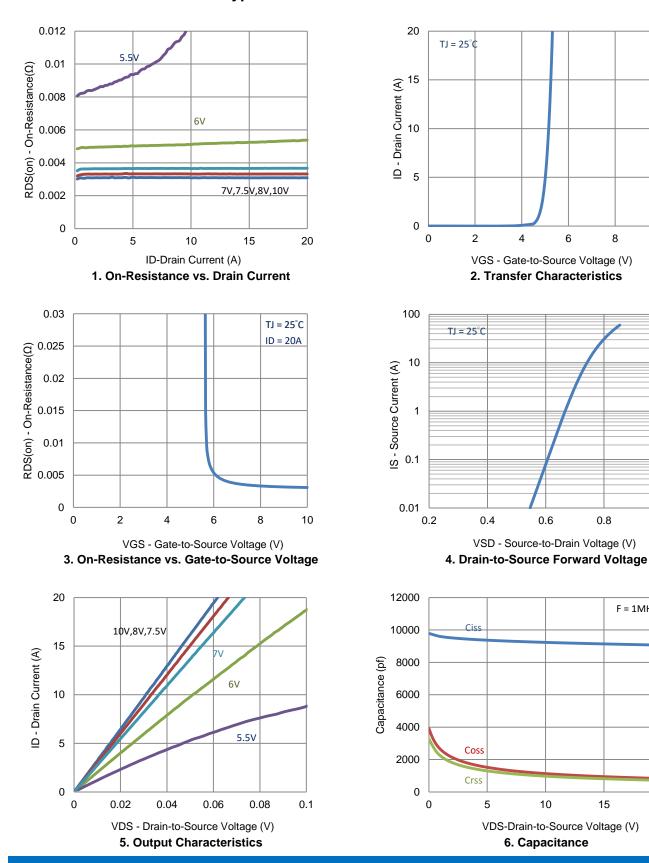
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10

1

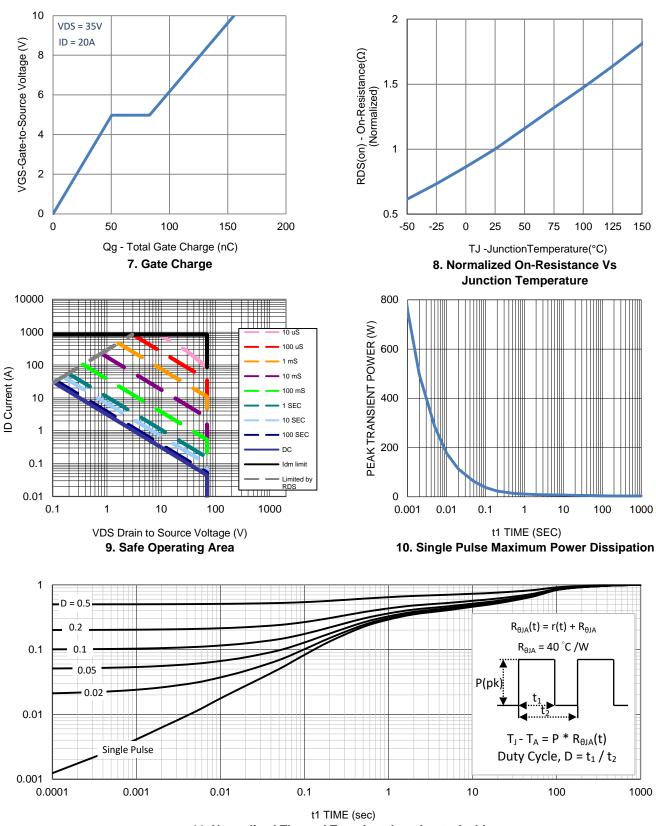
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F = 1MHz



Typical Electrical Characteristics

15

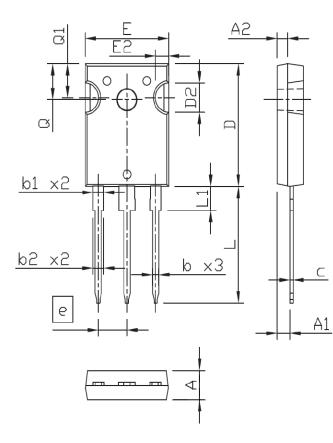


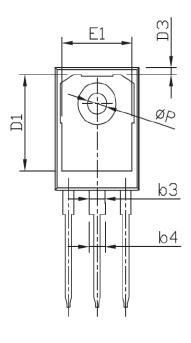
Typical Electrical Characteristics

11. Normalized Thermal Transient Junction to Ambient

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Package Information





SYMBOLS	DIMENSIONS IN MILLIMETERS					
STMBULS	MIN	NDM	MAX			
Α	4,90	5,00	5.10			
A1	2,32	2.42	2.52			
A2	1,90	2,00	2,10			
b	1.17	1.22	1.27			
b1	1,97	2,02	2.07			
b2	2.00	2.10	2,20			
b3	2,97	3.02	3,07			
b4	3.00	3.10 0.62	3.20			
C D	0.59	0.62	0.66			
D	20,90	21,00	21,10			
D1	16.25	16.55	16.85			
D2		5,00 TYP	,			
D3	1.05	1.20	1.35			
е		5,44 BSC				
e E	15.70	15.80	15.90			
E1	13.06	13.26	13,46			
E2	2,50 TYP					
L	19.72	19.92	20,12			
L1			4,30			
Q	6.15 BSC					
Q1	5,60	5.80	6.00			
ØΡ	3.55	3.60	3.65			